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**Advanced Semiconductor Fundamentals**-Robert F. Pierret 1987-01-01

**Fundamentals of Semiconductor Fabrication**-Gary S. May 2004 Offers a basic, up-to-date introduction to semiconductor fabrication technology, including both the theoretical and practical aspects of all major steps in the fabrication sequence Presents comprehensive coverage of process sequences Introduces readers to modern simulation tools Addresses the practical aspects of integrated circuit fabrication Clearly explains basic processing theory

**Fundamentals of Semiconductor Manufacturing and Process Control**

Gary S. May 2006-05-26 A practical guide to semiconductor manufacturing from process control to yield modeling and experimental design Fundamentals of Semiconductor Manufacturing and Process Control covers all issues involved in manufacturing microelectronic devices and circuits, including fabrication sequences, process control, experimental design, process modeling, yield modeling, and CIM/CAM systems. Readers are introduced to both the theory and practice of all basic manufacturing concepts. Following an overview of manufacturing and technology, the text explores process monitoring methods, including those that focus on product wafers and those that focus on the equipment used to produce wafers. Next, the text sets forth some fundamentals of statistics and yield modeling, which set the foundation for a detailed discussion of how statistical process control is used to analyze quality and improve yields. The discussion of statistical experimental design offers readers a powerful approach for systematically varying controllable process conditions and determining their impact on output parameters that measure quality. The authors introduce process modeling concepts, including several advanced process control topics such as run-by-run, supervisory control, and process and equipment diagnosis. Critical coverage includes the following: \* Combines process control and semiconductor manufacturing \* Unique treatment of system and software technology and management of overall manufacturing systems \* Chapters include case studies, sample problems, and suggested exercises \* Instructor support includes electronic copies of the figures and an instructor's manual Graduate-level students and industrial practitioners will benefit from the detailed examination of how electronic materials and supplies are converted into finished integrated circuits and electronic products in a high-volume manufacturing environment. An Instructor's Manual presenting detailed solutions to all the problems in the book is available from the Wiley editorial department. An Instructor Support FTP site is also available.

**Field Effect Devices**-Robert F. Pierret 1990 The second edition examines in detail three of the most basic members of the field device family to introduce the reader to relevant terms, concepts, models, and analytical procedures.

**Semiconductor Device Fundamentals**-Robert F. Pierret 1996-09

**Semiconductor fundamentals**-Robert F. Pierret 1983

**Fundamentals of Semiconductor Devices**-Richard L. Anderson 2004-03-12 Fundamentals of Semiconductor Devices provides a realistic and practical treatment of modern semiconductor devices. A solid understanding of the physical processes responsible for the electronic properties of semiconductor materials and devices is emphasized. With this emphasis, the reader will appreciate the underlying physics behind the equations derived and their range of applicability. The author's clear writing style, comprehensive coverage of the core material, and attention to

current topics are key strengths of this book.

**Fundamentals of Semiconductors**-Peter YU 2005-03-23 Excellent bridge between general solid-state physics textbook and research articles packed with providing detailed explanations of the electronic, vibrational, transport, and optical properties of semiconductors "The most striking feature of the book is its modern outlook ... provides a wonderful foundation. The most wonderful feature is its efficient style of exposition ... an excellent book." Physics Today "Presents the theoretical derivations carefully and in detail and gives thorough discussions of the experimental results it presents. This makes it an excellent textbook both for learners and for more experienced researchers wishing to check facts. I have enjoyed reading it and strongly recommend it as a text for anyone working with semiconductors ... I know of no better text ... I am sure most semiconductor physicists will find this book useful and I recommend it to them." Contemporary Physics Offers much new material: an extensive appendix about the important and by now well-established, deep center known as the DX center, additional problems and the solutions to over fifty of the problems at the end of the various chapters.

**Semiconductor Material and Device Characterization**-Dieter K. Schroder 2006 Resistivity -- Carrier and doping density -- Contact resistance and Schottky barriers -- Series resistance, channel length and width, and threshold voltage -- Defects -- Oxide and interface trapped charges, oxide thickness -- Carrier lifetimes -- Mobility -- Charge-based and probe characterization -- Optical characterization -- Chemical and physical characterization -- Reliability and failure analysis.

**Semiconductor Device Fundamentals**-Robert F. Pierret 1996 Special Features \*Computer-based exercises and homework problems -- unique to this text and comprising 25% of the total number of problems -- encourage students to address realistic and challenging problems, experiment with what if scenarios, and easily obtain graphical outputs. Problems are designed to progressively enhance MATLAB-use proficiency, so students need not be familiar with MATLAB at the start of your course. Program scripts that are answers to exercises in the text are available at no charge in electronic form (see Teaching Resources below). \*Supplement and Review Mini-Chapters after each of the text's three parts contain an extensive review list of terms, test-like problem sets with answers, and detailed suggestions on supplemental reading to reinforce students' learning and help them prepare for exams. \*Read-Only Chapters, strategically placed to provide a change of pace during the course, provide informative, yet enjoyable reading for students. \*Measurement Details and Results samples offer students a realistic perspective on the seldom-perfect nature of device characteristics, contrary to the way they are often represented in introductory texts. Content Highlig

**Physics of Semiconductor Devices**-Simon M. Sze 2006-11-03 The Third Edition of the standard textbook and reference in the field of semiconductor devices This classic book has set the standard for advanced study and reference in the semiconductor device field. Now completely updated and reorganized to reflect the tremendous advances in device concepts and performance, this Third Edition remains the most detailed and exhaustive single source of information on the most important semiconductor devices. It gives readers immediate access to detailed descriptions of the underlying physics and performance characteristics of all major bipolar, field-effect, microwave, photonic, and sensor devices. Designed for graduate textbook adoptions and reference needs, this new edition includes: A complete update of the latest developments New devices such as three-dimensional MOSFETs, MODFETs, resonant-tunneling diodes, semiconductor sensors, quantum-cascade lasers, single-electron transistors, real-space transfer devices, and more Materials completely reorganized Problem sets at the end of each chapter All figures reproduced at the highest quality Physics of Semiconductor Devices, Third Edition offers engineers, research scientists, faculty, and students a practical basis for understanding the most important

devices in use today and for evaluating future device performance and limitations. A Solutions Manual is available from the editorial department.

**Advanced Theory of Semiconductor Devices**-Karl Hess 2000 Electrical Engineering Advanced Theory of Semiconductor Devices Semiconductor devices are ubiquitous in today's world and are found increasingly in cars, kitchens and electronic door locks, attesting to their presence in our daily lives. This comprehensive book provides the fundamentals of semiconductor device theory from basic quantum physics to computer-aided design. Advanced Theory of Semiconductor Devices will improve your understanding of computer simulation of devices through a thorough discussion of basic equations, their validity, and numerical solutions as they are contained in current simulation tools. You will gain state-of-the-art knowledge of devices used in both III-V compounds and silicon technology. Specially featured are novel approaches and explanations of electronic transport, particularly in p-n junction diodes. Close attention is also given to innovative treatments of quantum-well laser diodes and hot electron effects in silicon technology. This in-depth book is written for engineers, graduate students, and research scientists in solid-state electronics who want to gain a better understanding of the principles underlying semiconductor devices.

**Quantum Mechanics for Applied Physics and Engineering**-Albert T. Fromhold 2012-07-26 For upper-level undergraduates and graduate students: an introduction to the fundamentals of quantum mechanics, emphasizing aspects essential to an understanding of solid-state theory. Numerous problems (and selected answers), projects, exercises.

**Optical Properties of Solids**-Mark Fox 2010-03-25 For final year undergraduates and graduate students in physics, this book offers an up-to-date treatment of the optical properties of solid state materials.

**VLSI Fabrication Principles**-Sorab K. Ghandhi 1994-03-28 In some places, the order of presentation has been changed to fine-tune the book's effectiveness as a senior and graduate-level teaching text. Fabrication principles covered include those for such circuits as CMOS, BIPOLAR, BICMOS, FET, and more.

**Fundamentals of Structural Dynamics**-Roy R. Craig 2011-08-24 From theory and fundamentals to the latest advances in computational and experimental modal analysis, this is the definitive, updated reference on structural dynamics. This edition updates Professor Craig's classic introduction to structural dynamics, which has been an invaluable resource for practicing engineers and a textbook for undergraduate and graduate courses in vibrations and/or structural dynamics. Along with comprehensive coverage of structural dynamics fundamentals, finite-element-based computational methods, and dynamic testing methods, this Second Edition includes new and expanded coverage of computational methods, as well as introductions to more advanced topics, including experimental modal analysis and "active structures." With a systematic approach, it presents solution techniques that apply to various engineering disciplines. It discusses single degree-of-freedom (SDOF) systems, multiple degrees-of-freedom (MDOF) systems, and continuous systems in depth; and includes numeric evaluation of modes and frequency of MDOF systems; direct integration methods for dynamic response of SDOF systems and MDOF systems; and component mode synthesis. Numerous illustrative examples help engineers apply the techniques and methods to challenges they face in the real world. MATLAB(r) is extensively used throughout the book, and many of the .m-files are made available on the book's Web site. Fundamentals of Structural Dynamics, Second Edition is an indispensable reference and "refresher course" for engineering professionals; and a textbook for seniors or graduate students in mechanical engineering, civil engineering, engineering mechanics, or aerospace engineering.

**Physics of Semiconductor Devices**-Simon M. Sze 2021-03-03 The new edition of the most detailed and comprehensive single-volume reference on major semiconductor devices The Fourth Edition of Physics of Semiconductor Devices remains the standard reference work on the fundamental physics and operational characteristics of all major bipolar, unipolar, special microwave, and optoelectronic devices. This fully updated and expanded edition includes approximately 1,000 references to original research papers and review articles, more than 650 high-quality technical illustrations, and over two dozen tables of material parameters. Divided into five parts, the text first provides a summary of semiconductor properties, covering energy band, carrier concentration, and transport properties. The second part surveys the basic building blocks of semiconductor devices,

including p-n junctions, metal-semiconductor contacts, and metal-insulator-semiconductor (MIS) capacitors. Part III examines bipolar transistors, MOSFETs (MOS field-effect transistors), and other field-effect transistors such as JFETs (junction field-effect-transistors) and MESFETs (metal-semiconductor field-effect transistors). Part IV focuses on negative-resistance and power devices. The book concludes with coverage of photonic devices and sensors, including light-emitting diodes (LEDs), solar cells, and various photodetectors and semiconductor sensors. This classic volume, the standard textbook and reference in the field of semiconductor devices: Provides the practical foundation necessary for understanding the devices currently in use and evaluating the performance and limitations of future devices Offers completely updated and revised information that reflects advances in device concepts, performance, and application Features discussions of topics of contemporary interest, such as applications of photonic devices that convert optical energy to electric energy Includes numerous problem sets, real-world examples, tables, figures, and illustrations; several useful appendices; and a detailed solutions manual Explores new work on leading-edge technologies such as MODFETs, resonant-tunneling diodes, quantum-cascade lasers, single-electron transistors, real-space-transfer devices, and MOS-controlled thyristors Physics of Semiconductor Devices, Fourth Edition is an indispensable resource for design engineers, research scientists, industrial and electronics engineering managers, and graduate students in the field.

**Advanced Semiconductor Devices**-Michael S. Shur 2007 This volume covers five emerging areas of advanced device technology: wide band gap devices, terahertz and millimeter waves, nanometer silicon and silicon-germanium devices, nanoelectronics and ballistic devices, and the characterization of advanced photonic and electronic devices. The papers by leading researchers in high speed and advanced electronic and photonic technology presented many firsts and breakthrough results, as has become a tradition with the Lester Eastman Conference, and will allow readers to obtain up-to-date information about emerging trends and future directions of these technologies. Key papers in each section present snap-shot and mini reviews of state-of-the-art and hot off the press results making the book required reading for engineers, scientists, and students working on advanced and high speed device technology.

**Fundamental Accounting Principles**-William W. Pyle 1984

**Fundamentals of Carrier Transport**-Mark Lundstrom 2009-07-02 An accessible introduction to the behaviour of charged carriers in semiconductors and semiconductor devices.

**Nanoscale Transistors**-Mark Lundstrom 2006-06-18 To push MOSFETs to their scaling limits and to explore devices that may complement or even replace them at molecular scale, a clear understanding of device physics at nanometer scale is necessary. Nanoscale Transistors provides a description on the recent development of theory, modeling, and simulation of nanotransistors for electrical engineers, physicists, and chemists working on nanoscale devices. Simple physical pictures and semi-analytical models, which were validated by detailed numerical simulations, are provided for both evolutionary and revolutionary nanotransistors. After basic concepts are reviewed, the text summarizes the essentials of traditional semiconductor devices, digital circuits, and systems to supply a baseline against which new devices can be assessed. A nontraditional view of the MOSFET using concepts that are valid at nanoscale is developed and then applied to nanotube FET as an example of how to extend the concepts to revolutionary nanotransistors. This practical guide then explore the limits of devices by discussing conduction in single molecules

**An Introduction to Semiconductor Devices**-Donald A. Neamen 2006 An Introduction to Semiconductor Devices by Donald Neamen provides an understanding of the characteristics, operations and limitations of semiconductor devices. In order to provide this understanding, the book brings together the fundamental physics of the semiconductor material and the semiconductor device physics. This new text provides an accessible and modern presentation of material. Quantum mechanic material is minimal, and the most advanced material is designated with an icon. This modern approach means that coverage of the MOS transistor precedes the material on the bipolar transistor, which reflects the dominance of MOS technology in today's world. Excellent pedagogy is present throughout the book in the form of interesting chapters openers, worked examples, a variety of exercises, key terms, and end of chapter problems.

**Energy-Level Control at Hybrid Inorganic/Organic Semiconductor**

**Interfaces**-Raphael Schlesinger 2016-11-21 This work investigates the energy-level alignment of hybrid inorganic/organic systems (HIOS) comprising ZnO as the major inorganic semiconductor. In addition to offering essential insights, the thesis demonstrates HIOS energy-level alignment tuning within an unprecedented energy range. (Sub)monolayers of organic molecular donors and acceptors are introduced as an interlayer to modify HIOS interface-energy levels. By studying numerous HIOS with varying properties, the author derives generally valid systematic insights into the fundamental processes at work. In addition to molecular pinning levels, he identifies adsorption-induced band bending and gap-state density of states as playing a crucial role in the interlayer-modified energy-level alignment, thus laying the foundation for rationally controlling HIOS interface electronic properties. The thesis also presents quantitative descriptions of many aspects of the processes, opening the door for innovative HIOS interfaces and for future applications of ZnO in electronic devices.

**Solid State Physics**-J. S. Blakemore 1985-12-12 Updated to reflect recent work in the field, this book emphasizes crystalline solids, going from the crystal lattice to the ideas of reciprocal space and Brillouin zones, and develops these ideas for lattice vibrations, for the theory of metals, and for semiconductors. The theme of lattice periodicity and its varied consequences runs through eighty percent of the book. Other sections deal with major aspects of solid state physics controlled by other phenomena: superconductivity, dielectric and magnetic properties, and magnetic resonance.

**Mechanics of Machinery**-Mahmoud A. Mostafa 2012-11-07 Mechanics of Machinery describes the analysis of machines, covering both the graphical and analytical methods for examining the kinematics and dynamics of mechanisms with low and high pairs. This text, developed and updated from a version published in 1973, includes analytical analysis for all topics discussed, allowing for the use of math software

**Electromechanical Motion Devices**-Paul Krause 2012-08-10 This text provides a basic treatment of modern electric machine analysis that gives readers the necessary background for comprehending the traditional applications and operating characteristics of electric machines—as well as their emerging applications in modern power systems and electric drives, such as those used in hybrid and electric vehicles. Through the appropriate use of reference frame theory, *Electromagnetic Motion Devices, Second Edition* introduces readers to field-oriented control of induction machines, constant-torque, and constant-power control of dc, permanent-magnet machines, and brushless dc machines. It also discusses steady-state and transient performance in addition to their applications. *Electromagnetic Motion Devices, Second Edition* presents: The derivations of all machine models, starting with a common first-principle approach (based upon Ohm's, Faraday's, Ampere's, and Newton's/Euler's laws) A generalized two-phase approach to reference frame theory that can be applied to the ac machines featured in the book The influences of the current and voltage constraints in the torque-versus-speed profile of electric machines operated with an electric drive Complete with slides, videos, animations, problems & solutions Thoroughly classroom tested and complete with a supplementary solutions manual and video library, *Electromagnetic Motion Devices, Second Edition* is an invaluable book for anyone interested in modern machine theory and applications. If you would like access to the solutions manual and video library, please send an email to: [ieeeproposals@wiley.com](mailto:ieeeproposals@wiley.com).

**Semiconductor Device Physics and Design**-Umesh Mishra 2007-11-28 *Semiconductor Device Physics and Design* teaches readers how to approach device design from the point of view of someone who wants to improve devices and can see the opportunity and challenges. It begins with coverage of basic physics concepts, including the physics behind polar heterostructures and strained heterostructures. The book then details the important devices ranging from p-n diodes to bipolar and field effect devices. By relating device design to device performance and then relating device needs to system use the student can see how device design works in the real world.

**Semiconductor Physics And Devices**-Neamen 1992

**Microelectronic Circuit Design**-Richard Jaeger 2015-02-27 Richard Jaeger and Travis Blalock present a balanced coverage of analog and digital circuits; students will develop a comprehensive understanding of the basic techniques of modern electronic circuit design, analog and digital, discrete

and integrated. A broad spectrum of topics are included in *Microelectronic Circuit Design* which gives the professor the option to easily select and customize the material to satisfy a two-semester or three-quarter sequence in electronics. Jaeger/Blalock emphasizes design through the use of design examples and design notes. Excellent pedagogical elements include chapter opening vignettes, chapter objectives, "Electronics in Action" boxes, a problem-solving methodology, and "Design Note" boxes. The use of the well-defined problem-solving methodology presented in this text can significantly enhance an engineer's ability to understand the issues related to design. The design examples assist in building and understanding the design process.

**Introduction to Telecommunications Network Engineering, Second Edition**-Tarmo Anttalainen 2003 Whether you are an executive or sales manager in a networking company, a data communications engineer, or a telecommunications professional, you must have a thorough working knowledge of the ever growing and interrelated array of telecom and data communications technologies. From protocols and operation of the Internet (IP, TCP, HTTP, ...) and its access systems such as ADSL, and GSM... to the basics of transmission and switching, this newly revised resource delivers an up-to-date introduction to a broad range of networking technologies, clearly explaining the networking essentials you need to know to be a successful networking professional. Moreover, the book explores the future developments in optical, wireless and digital broadcast communications.

**Incompressible Flow**-Ronald L. Panton 2013-08-05 The most teachable book on incompressible flow— now fully revised, updated, and expanded *Incompressible Flow, Fourth Edition* is the updated and revised edition of Ronald Panton's classic text. It continues a respected tradition of providing the most comprehensive coverage of the subject in an exceptionally clear, unified, and carefully paced introduction to advanced concepts in fluid mechanics. Beginning with basic principles, this Fourth Edition patiently develops the math and physics leading to major theories. Throughout, the book provides a unified presentation of physics, mathematics, and engineering applications, liberally supplemented with helpful exercises and example problems. Revised to reflect students' ready access to mathematical computer programs that have advanced features and are easy to use, *Incompressible Flow, Fourth Edition* includes: Several more exact solutions of the Navier-Stokes equations Classic-style Fortran programs for the Hiemenz flow, the Psi-Omega method for entrance flow, and the laminar boundary layer program, all revised into MATLAB A new discussion of the global vorticity boundary restriction A revised vorticity dynamics chapter with new examples, including the ring line vortex and the Fraenkel-Norbury vortex solutions A discussion of the different behaviors that occur in subsonic and supersonic steady flows Additional emphasis on composite asymptotic expansions *Incompressible Flow, Fourth Edition* is the ideal coursebook for classes in fluid dynamics offered in mechanical, aerospace, and chemical engineering programs.

**Electronic and Optoelectronic Properties of Semiconductor Structures**-Jasprit Singh 2007-03-26 A graduate textbook presenting the underlying physics behind devices that drive today's technologies. The book covers important details of structural properties, band structure, transport, optical and magnetic properties of semiconductor structures. Effects of low-dimensional physics and strain - two important driving forces in modern device technology - are also discussed. In addition to conventional semiconductor physics the book discusses self-assembled structures, mesoscopic structures and the developing field of spintronics. The book utilizes carefully chosen solved examples to convey important concepts and has over 250 figures and 200 homework exercises. Real-world applications are highlighted throughout the book, stressing the links between physical principles and actual devices. *Electronic and Optoelectronic Properties of Semiconductor Structures* provides engineering and physics students and practitioners with complete and coherent coverage of key modern semiconductor concepts. A solutions manual and set of viewgraphs for use in lectures are available for instructors, from [solutions@cambridge.org](mailto:solutions@cambridge.org).

**Nanostructured Ceramics**-Debasish Sarkar 2018-09-03 This book discusses fundamentals of nanostructured ceramics involving functional, structural and high temperature materials. It provides both solved numerical problems and unsolved problems to enable the reader to envisage the correlation between synthesis process and properties in the perspective of new material development. It serves as a concise text to answer the basics and achieve research goals for academia and industry. Key Features Deals with basic strategy on data interpretation for nanostructured ceramics Proposes to bridge the gap between the nano and bulk properties of nanostructured ceramics Discusses brief schematics and equations to understand the different properties of nano to bulk ceramics Presents mode

of data acquisition and interpretation through statistical module and solved numerical Includes unsolved numericals based on properties, data acquisition and interpretation

**Semiconductor Devices : Basic Principles**-Jaspri Singh 2007

Market\_Desc: · Electrical Engineers Special Features: · Over 150 solved examples that clarify concepts are integrated throughout the text. · End-of-chapter summary tables and hundreds of figures are included to reinforce the intricacies of modern semiconductor devices· Coverage of device optimization issues shows the reader how in each device one has to trade one performance against another About The Book: This introductory text presents a well-balanced coverage of semiconductor physics and device operation and shows how devices are optimized for applications. The text begins with an exploration of the basic physical processes upon which all semiconductor devices are based. Next, the author focuses on the operation of the important semiconductor devices along with issues relating to the optimization of device performance.

**Solid State and Semiconductor Physics**-John P. Mckelvey 1985

**SEMICONDUCTOR DEVICES: PHYSICS AND TECHNOLOGY, 2ND ED-**

S.M.Sze 2008-06 Market\_Desc: · Electrical Engineers· Scientists Special Features: · Provides strong coverage of all key semiconductor devices. Includes basic physics and material properties of key semiconductors· Covers all important processing technologies About The Book: This book is an introduction to the physical principles of modern semiconductor devices and their advanced fabrication technology. It begins with a brief historical review of major devices and key technologies and is then divided into three sections: semiconductor material properties, physics of semiconductor devices and processing technology to fabricate these semiconductor devices.

**Handbook of Photovoltaic Science and Engineering**-Antonio Luque

2011-03-29 The most comprehensive, authoritative and widely cited reference on photovoltaic solar energy Fully revised and updated, the Handbook of Photovoltaic Science and Engineering, Second Edition incorporates the substantial technological advances and research developments in photovoltaics since its previous release. All topics relating to the photovoltaic (PV) industry are discussed with contributions by distinguished international experts in the field. Significant new coverage includes: three completely new chapters and six chapters with new authors device structures, processing, and manufacturing options for the three major thin film PV technologies high performance approaches for multijunction, concentrator, and space applications new types of organic polymer and dye-sensitized solar cells economic analysis of various policy options to stimulate PV growth including effect of public and private investment Detailed treatment covers: scientific basis of the photovoltaic effect and solar cell operation the production of solar silicon and of silicon-based solar cells and modules how choice of semiconductor materials and their production influence costs and performance making measurements on solar cells and modules and how to relate results under standardised test conditions to real outdoor performance photovoltaic system installation and operation of components such as inverters and batteries. architectural applications of building-integrated PV Each chapter is structured to be partially accessible to beginners while providing detailed information of the physics and technology for experts. Encompassing a review of past work and the fundamentals in solar electric science, this is a leading reference and invaluable resource for all practitioners, consultants, researchers and students in the PV industry.

**Introduction to Semiconductor Devices**-Kevin F. Brennan 2005-02-03

From semiconductor fundamentals to semiconductor devices used in the telecommunications and computing industries, this 2005 book provides a solid grounding in the most important devices used in the hottest areas of electronic engineering. The book includes coverage of future approaches to computing hardware and RF power amplifiers, and explains how emerging trends and system demands of computing and telecommunications systems influence the choice, design and operation of semiconductors. Next, the field effect devices are described, including MODFETs and MOSFETs. Short channel effects and the challenges faced by continuing miniaturisation are then addressed. The rest of the book discusses the structure, behaviour, and operating requirements of semiconductor devices used in lightwave and wireless telecommunications systems. This is both an excellent senior/graduate text, and a valuable reference for engineers and researchers in the field.

**Modern Semiconductor Device Physics**-Sze 1998 An in-depth, up-to-date

presentation of the physics and operational principles of all modern semiconductor devices The companion volume to Dr. Sze's classic Physics of Semiconductor Devices, Modern Semiconductor Device Physics covers all the significant advances in the field over the past decade. To provide the most authoritative, state-of-the-art information on this rapidly developing technology, Dr. Sze has gathered the contributions of world-renowned experts in each area. Principal topics include bipolar transistors, compound-semiconductor field-effect-transistors, MOSFET and related devices, power devices, quantum-effect and hot-electron devices, active microwave diodes, high-speed photonic devices, and solar cells. Supported by hundreds of illustrations and references and a problem set at the end of each chapter, Modern Semiconductor Device Physics is the essential text/reference for electrical engineers, physicists, material scientists, and graduate students actively working in microelectronics and related fields.

**Theory and Practice of Water and Wastewater Treatment**-Ronald L.

Droste 2018-07-31 Provides an excellent balance between theory and applications in the ever-evolving field of water and wastewater treatment Completely updated and expanded, this is the most current and comprehensive textbook available for the areas of water and wastewater treatment, covering the broad spectrum of technologies used in practice today—ranging from commonly used standards to the latest state of the art innovations. The book begins with the fundamentals—applied water chemistry and applied microbiology—and then goes on to cover physical, chemical, and biological unit processes. Both theory and design concepts are developed systematically, combined in a unified way, and are fully supported by comprehensive, illustrative examples. Theory and Practice of Water and Wastewater Treatment, 2nd Edition: Addresses physical/chemical treatment, as well as biological treatment, of water and wastewater Includes a discussion of new technologies, such as membrane processes for water and wastewater treatment, fixed-film biotreatment, and advanced oxidation Provides detailed coverage of the fundamentals: basic applied water chemistry and applied microbiology Fully updates chapters on analysis and constituents in water; microbiology; and disinfection Develops theory and design concepts methodically and combines them in a cohesive manner Includes a new chapter on life cycle analysis (LCA) Theory and Practice of Water and Wastewater Treatment, 2nd Edition is an important text for undergraduate and graduate level courses in water and/or wastewater treatment in Civil, Environmental, and Chemical Engineering.